TOSHIBA TSZ1J2A45-N

TOSHIBA SOLID DTATE AC RELAY

T S Z 1 J 2 A 4 5 - N

OPTICALLY ISOLATED, NORMALLY OPEN DUAL IN ONE PACKAGE TYPE **SSR**

COMPUTER PERIPHERALS

MACHINE TOOL CONTROLS

PROCESS CONTROL SYSTEMS

TRAFFIC CONTROL SYSTEMS

R.M.S On-State Current : $I_{T(RMS)}=1A$

Non-Repetitive Peak Off-State Voltage: VDSM=600V

TTL Compatible

: 2000V AC (t=1min.)Isolation Voltage

MAXIMUM RATINGS (Ta = 25°C, EACH CIRCUIT) INPUT (CONTROL)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Control Input Current (DC) (Note 1)	I _{F (IN)}	30	mA
Input Reverse Voltage (DC)	$I_{R(IN)}$	5	V

29.5MAX 7 MAX TYPE MARK 24 MAX 5 6 7 0.46 a: 2.54 b: 5.08 (1.6)c: 1. OUTPUT A (AC) OUTPUT B (AC) OUTPUT COMMON (AC) 4. INPUT A(+) 6. INPUT B(+)INPUT A(-) 7. INPUT B(-)**JEDEC EIAJ** TOSHIBA 10-30E1A

Unit in mm

OUTPUT (LOAD)

Non-Repetitive Peak Off-State Voltage	$V_{ m DSM}$	600	V
Nominal AC Line Voltage	v_{AC}	240	V
R.M.S On-State Current	I _T (RMS)	1	A
Peak One Cycle Surge On-State Current (Non-Repetitive)	I _{TSM}	40 (50Hz) 44 (60Hz)	A
Operating Frequency Range	f	45~65	Hz
Isolation Voltage (t=1min., Input to Output)	BVS/AC	2000	V
Operating Temperature Range	$T_{ m opr}$	-20~80	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-30~100	°C

- Note 1: Not Including Input Resistance: Used Insert an external resistance into SSR. Reverse voltage should not be applied to input.
 - 2: Sunbber network (C-R) is necessary to protect from surge voltage and dv/dt fire. Sunbber network is to be connected between #1, #2, and #3 terminal.
 - 3: Mounting: Soldering of printed wiring board should be used under 260°C and 10 second.

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ELECTRICAL CHARACTERISTICS (Ta = 25°C, EACH CIRCUIT) INPUT (CONTROL)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Pick Up Current	I_{FT}	V _{AC} =100V _{rms} , Resistive Load	_	_	12	mA
Drop Out Voltage	$ m v_{FD}$		0.5	_	_	V
Input Resistance	R _(IN)	_	_	0	_	Ω

OUTPUT (LOAD)

Off-State Leakage Current	$I_{ m OL}$	$V_{AC} = 200 V_{rms}$, $f = 50 Hz$	-	1	1.0	mA
Peak On-State Voltage	$V_{ extbf{TM}}$	$I_{T(RMS)} = 1A$	1	1	1.5	V
dv / dt (Off-State)	dv / dt	$V_{DSM} = 0.7 \times Rated$	50	1	_	V/μs
Turn-On Time	t_{on}	$V_{ m AC} = 100 m Vrms$,	1	1	1	ms
Turn-Off Time	$t_{ ext{off}}$	Resistive Load (Fig. 1)	_	_	1/2	Cycle
Isolation Resistance	$R_{\mathbf{S}}$	$V = 500V, R_H = 40 \sim 60\%$	10^{10}	10^{11}	_	Ω

EQUIVALENT CIRCUIT

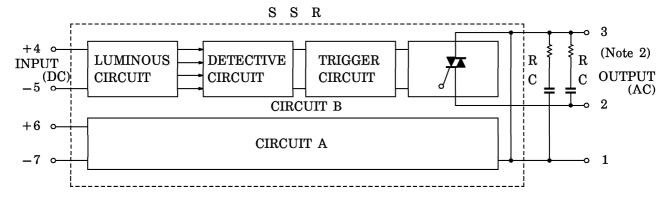
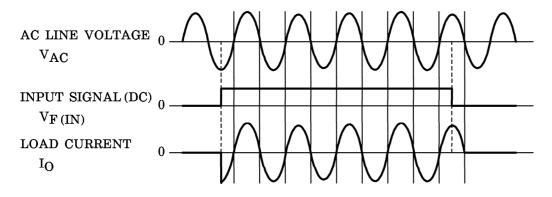


Fig. 1. SWITCHING WAVEFORM



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